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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/662,028	09/12/2003	Stephen W. Bedell	YOR920030203US1 (16694)	9297	
23389 75	590 08/24/2005 ·		EXAMINER		
SCULLY SCOTT MURPHY & PRESSER, PC			WYSZOMIERS	WYSZOMIERSKI, GEORGE P	
400 GARDEN CITY PLAZA SUITE 300 GARDEN CITY, NY 11530			ART UNIT	PAPER NUMBER	
			1742		
			DATE MAILED: 08/24/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

•	Application No.	Applicant(s)					
	10/662,028	BEDELL ET AL.					
Office Action Summary	Examiner	Art Unit					
	George P. Wyszomierski	1742					
The MAILING DATE of this communication apperiod for Reply	ppears on the cover sheet with the	correspondence address					
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	I. I.136(a). In no event, however, may a reply be ti eply within the statutory minimum of thirty (30) da d will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONI	mely filed ys will be considered timely. In the mailing date of this communication. ED (35 U.S.C. § 133).					
Status							
1) Responsive to communication(s) filed on							
· ·	nis action is non-final.	•					
·	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice under	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) Claim(s) 1-36 is/are pending in the application	Claim(s) <u>1-36</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdr	4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.	Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1 and 10-36</u> is/are rejected.							
7) Claim(s) 2-9 is/are objected to.	Claim(s) 2-9 is/are objected to.						
8) Claim(s) are subject to restriction and	or election requirement.						
Application Papers							
9) The specification is objected to by the Examir	ner.						
10) ☐ The drawing(s) filed on is/are: a) ☐ ac		Examiner.					
Applicant may not request that any objection to th		•					
Replacement drawing sheet(s) including the corre	ection is required if the drawing(s) is ol	ojected to. See 37 CFR 1.121(d).					
11) The oath or declaration is objected to by the I	Examiner. Note the attached Office	e Action or form PTO-152.					
Priority under 35 U.S.C. § 119	·						
12) Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. & 119(a	a)-(d) or (f)					
a) All b) Some * c) None of: 1. Certified copies of the priority documents. 2. Certified copies of the priority documents.	nts have been received.						
3. Copies of the certified copies of the pri application from the International Bure	iority documents have been receiv						
* See the attached detailed Office action for a list	, , , ,	ed.					
•		•					
Attachment(s)							
1) Notice of References Cited (PTO-892)	4) Interview Summary						
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08	Paper No(s)/Mail D 8) Dotice of Informal is	Patent Application (PTO-152)					
Paper No(s)/Mail Date <u>08/15/2005</u> .	6) Other:	, , (· · · · · · · · · · · · · ·					

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1. Claim 1 is objected to because, in line 4 of this claim, it appears that the word "one" should be deleted.

- 2. Claims 10-19 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. It is unclear whether the annealing step defined in claims 10 and 15 is the same as the annealing step recited in lines 5-6 of independent claim 1, or if these claims are defining a separate, additional annealing step. Claims 11-14 and 16-19 are included in this rejection as they depend from claims 10 and 15, respectively.
- 3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 4. Claims 1, 20-22, 24, 25 and 32 are rejected under 35 U.S.C. 102(e) as being anticipated by Huang et al. (U.S. patent 6,812,116).

With reference to Fig. 4A of Huang, the prior art discloses providing a Si-containing substrate having a hole rich region and a Ge-containing layer thereon. Huang discloses at column 3, lines 20-27 forming a porous region therein by anodizing using an HF-containing solution at a current density as recited in instant claim 22. Huang column 4, lines 15-22

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discloses annealing to achieve a relaxed SiGe-on-insulator structure. Huang discloses forming a cap layer comprising Si on this structure; see layer 18 of Huang Fig. 4A. Thus, all aspects of the claimed invention are held to be fully met by Huang et al.

5. Claims 1, 20, 21, 26, 29-31 and 36 are rejected under 35 U.S.C. 102(e) as being anticipated by Notsu et al. (U.S. Patent 6,828,214).

Notsu discloses providing a Si substrate having a region containing holes and a Ge containing layer on the substrate, forming a porous structure by anodizing using a solution containing HF (Notsu column 11, lines 22-26), and thermally oxidizing at a temperature within the range of instant claim 29 to form a surface oxide (Notsu column 12, lines 47-61). With respect to instant claim 36, the examiner is considering whatever amount of p-type dopant that may be present in the starting Si substrate to be "high", in accord with the instant claim. Thus, all aspects of the claimed invention are held to be fully disclosed by Notsu et al.

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 23, 26-31, and 33-35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Huang et al.

The Huang patent, discussed in item no. 4 supra, does not specify some of the parameters as recited in the instant claims. However, the claimed invention cannot be considered to be patentably distinguishable form the Huang disclosure because:

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a) With respect to instant claim 23, the anodization process of Huang, being performed under substantially the same conditions as that of the present invention, would be expected to result in a porosity level as presently claimed.

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- b) With respect to instant claims 26-31, if one's intent is to thermally oxidize a substance, it is axiomatic that one would want to use an oxygen-containing gas for this purpose. The most readily available such gas would be air, as recited in claim 28. The oxidizing step, by definition, would result in a "surface oxide or "thermal oxide" being present, as recited in claims 30 and 31. Finally, with respect to claim 29, one of ordinary skill in the art would have determined an appropriate temperature range in which to carry out the heat treatment of the prior art, and the range as claimed is well within that as generally known in the art.
- c) With respect to instant claims 33 and 34, while Huang does not specify the geometry of the hole-rich regions, performing the Huang process upon materials having the geometry of these regions as set forth in the instant claims would fall within the purview of the process as described by Huang.
- d) With respect to instant claim 35, the examiner's position is that performing a series of known steps any given number of times, to achieve nothing more than a cumulative and predictable effect of those steps, cannot define a patentable process.

Thus, a prima facie case of obviousness is established between the disclosure of Huang et al. and the presently claimed invention.

8. Claims 22-25, 27, 28, and 32-35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Notsu et al.

The prior art does not specifically disclose some of the parameters as recited in the instant claims. However, the claimed invention cannot be said to be patentably distinct from the Notsu disclosure because:

- a) With respect to instant claim 22, the current density range as presently claimed is a rather broad range which would encompass the majority of anodizing processes. It is thus a reasonable assumption that the anodizing step of Notsu utilizes a current density within the presently claimed range.
- b) With respect to instant claims 24 and 25, Notsu column 12, lines 15-17 indicates that steps as presently claimed would fall within the purview of the process as disclosed by Notsu.
- c) With respect to instant claim 32, Notsu column 12, line 65 thru column 13, line 5 indicates that a diffusion step may take place after the oxidation step. This would result in a process as defined in the present claim.
- d) With respect to instant claims 23, 27, 28, 33, 34 and 35, the remarks made in item 7 supra apply equally as well with respect to the Notsu reference.

Consequently, a prima facie case of obviousness is established between the disclosure of Notsu et al. and the presently claimed invention.

9. Claims 2-9 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims, and claims 10-19 would be allowable if rewritten to overcome the rejection(s) under 35 U.S.C. 112, 2nd paragraph, set forth in this Office action and to include all of the limitations of the base claim and any intervening claims. The prior art does not disclose or suggest a process as defined in instant claims 2, 3, 7,

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or 8. Thus, these claims and any claims dependent thereon are held to define patentable subject matter.

- 10. The remainder of the art cited on the attached PTO-892 and 1449 forms is of interest. This art is held to be no more relevant to the claimed invention than the art as applied in the rejections, supra.
- 11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to George Wyszomierski whose telephone number is (571) 272-1252. The examiner can normally be reached on Monday thru Friday from 8:00 a.m. to 4:30 p.m. Eastern time.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Roy King, can be reached on (571) 272-1244. Effective <u>July 15, 2005</u>, all patent application related correspondence transmitted by facsimile must be directed to the <u>new central facsimile number</u>, (571)-273-8300. This new Central FAX Number is the result of relocating the Central FAX server to the Office's Alexandria, Virginia campus.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

GEORGE WYSZOMIERSKI PRIMARY EXAMINER GROUP 1700

GPW August 19, 2005